

ROHS

HALOGEN FREE

Hyperfast Rectifier, 75 A FRED Pt® G5



LINKS TO ADDITIONAL RESOURCES

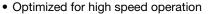




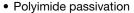
PRIMARY CHARACTERISTICS						
$I_{F(AV)}$	75 A					
V_R	1200 V					
V _F at I _F at 125 °C	1.85 V					
t _{rr}	40 ns					
T _J max.	175 °C					
Package	TO-247AD 2L					
Circuit configuration	Single					

FEATURES

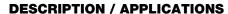
- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off







 Material categorization: for definitions of compliance please see www.vishav.com/doc?99912



Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V_{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	T _C = 103 °C, D = 0.50	75				
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	470	Α			
Repetitive peak forward current	I _{FRM}	T _C = 103 °C, D = 0.50, f = 20 kHz	150				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	1200	-	-			
Forward voltage	V _F	I _F = 75 A	-	2.0	2.6	V		
		I _F = 75 A, T _J = 125 °C	-	1.85	-			
Payaraa laakaga aurrant	I _R	V _R = V _R rated	-	-	50			
Reverse leakage current		T _J = 125 °C, V _R = V _R rated	-	-	500	μA		
Junction capacitance	C _T	V _R = 200 V	-	36	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH		



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		I _F = 1.0 A, dI _F /dt =	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		40	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	145	-	ns	
		T _J = 125 °C		-	220	-	†	
Peak recovery current	I	T _J = 25 °C	I _F = 50 A dI _F /dt = 600 A/μs	-	24	-	А	
Feak recovery current	I _{RRM}	T _J = 125 °C	$V_{R} = 400 \text{ V}$	-	43	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	1710	-	nC	
heverse recovery charge		T _J = 125 °C		-	4820	-		
Reverse recovery time		T _J = 25 °C	I _F = 75 A dI _F /dt = 1000 A/μs V _R = 800 V	-	115	-	ns	
heverse recovery time	t _{rr}	T _J = 125 °C		-	165	-		
Dook roopyony ourrent	I _{RRM}	T _J = 25 °C		-	42	-	А	
Peak recovery current		T _J = 125 °C		-	72	-		
Reverse recovery charge	0	T _J = 25 °C		-	2780	-	0	
	Q _{rr}	T _J = 125 °C		-	7100	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.36	°C/W		
Weight			-	5.5	-	g		
weight			-	0.2	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	=.	175	°C		
Marking device		Case style TO-247AD 2L	E5PH7512L					

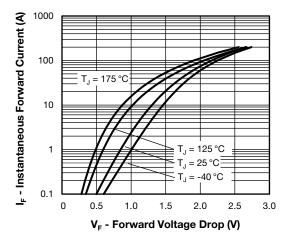


Fig. 1 - Forward Voltage Drop Characteristics

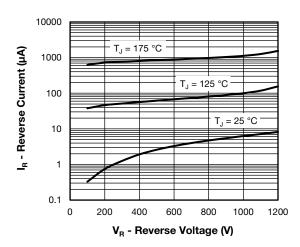


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

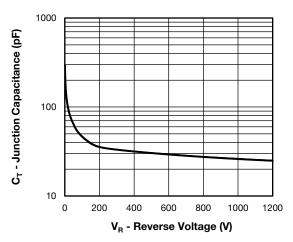


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

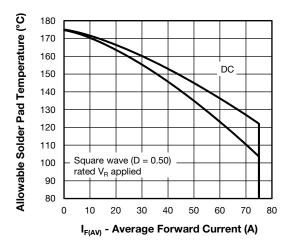


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

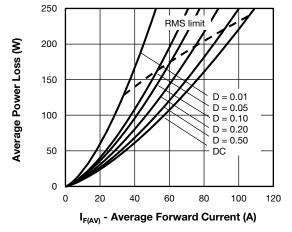


Fig. 5 - Forward Power Loss Characteristics

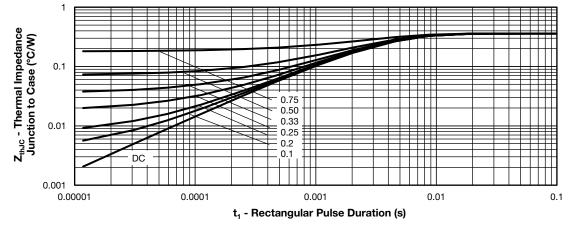
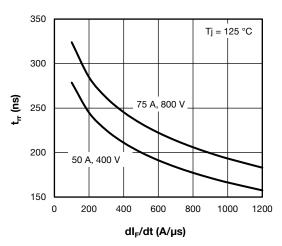


Fig. 6 - Transient Thermal Impedance, Junction to Case





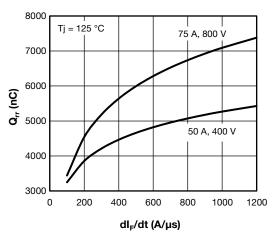


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

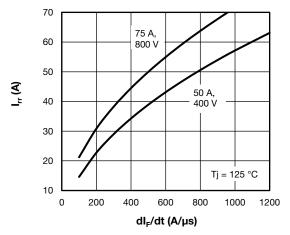


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt

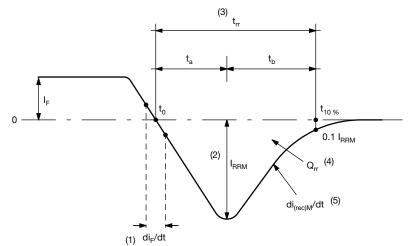


Fig. 10 - Reverse Recovery Waveform and Definitions

Notes

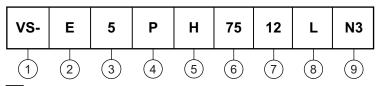
- (1) di_F/dt rate of change of current through zero crossing
- I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM} (4) Q_{rr} area under curve defined by t_0 and $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

(5) di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- Circuit configuration:

E = single diode, 2 pins

- FRED Pt Gen 5
- P = TO-247 package
- Process type:

H = hyperfast recovery

- Current rating (75 = 75 A)
- Voltage rating (12 = 1200 V)
- L = long lead
- Environmental digit:

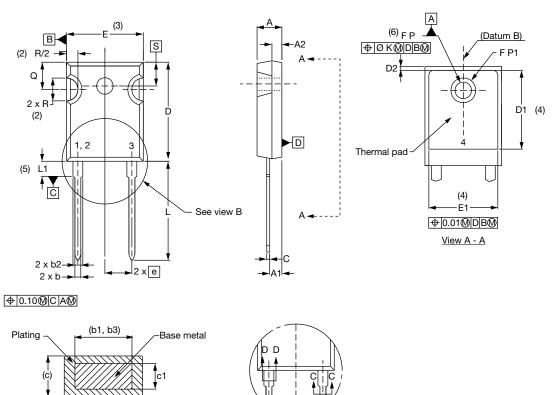
N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-E5PH7512L-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95536				
Part marking information	www.vishay.com/doc?95648				

TO-247AD 2L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIMETERS INCHES		HES	NOTES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

Section C - C, D - D

SYMBOL	MILLIN	IETERS	INC	INCHES		
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Е	15.29	15.87	0.602	0.625	3	
E1	13.46	-	0.53	-		
е	5.46	BSC	0.215	BSC		
ØK	0.2	254	0.010			
L	19.81	20.32	0.780	0.800		
L1	3.71	4.29	0.146	0.169		
ØΡ	3.56	3.66	0.14	0.144		
Ø P1	-	6.98	-	0.275		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	0.178	0.216		
S	5.51 BSC		0.217 BSC			
	•		•	•		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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